

DATA SHEET

| | |
|------------------|----------------|
| Part No. | AN12978A |
| Package Code No. | UBGA015-W-2020 |

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AN12978A

Monaural BTL amplifier IC with built-in AGC (I²C bus-control correspondence)

■ Overview

AN12978A is the monaural BTL amplifier which contained the AGC circuit for clip prevention of a speaker output. This IC performs a mode change by the I²C bus control system. (Standby function ON/OFF change etc.)

■ Features

- Selection by I²C bus control is possible in the on-level of AGC. (3-bit, 8-step)
- Selection by I²C bus control is possible in an attack/recovery time of AGC. (attack: 2-bit , recovery: 3-bit)
- The resistance and the capacitor of a detector circuit which were being used for the conventional AGC are unnecessary.
- In order to realize high efficiency of output power, it adopts CMOS power amplifier circuit.
- Built-in shutdown function.
- Built-in Gv-Switch.

■ Applications

- Audio amplifier for mobile, such as a cellular phone

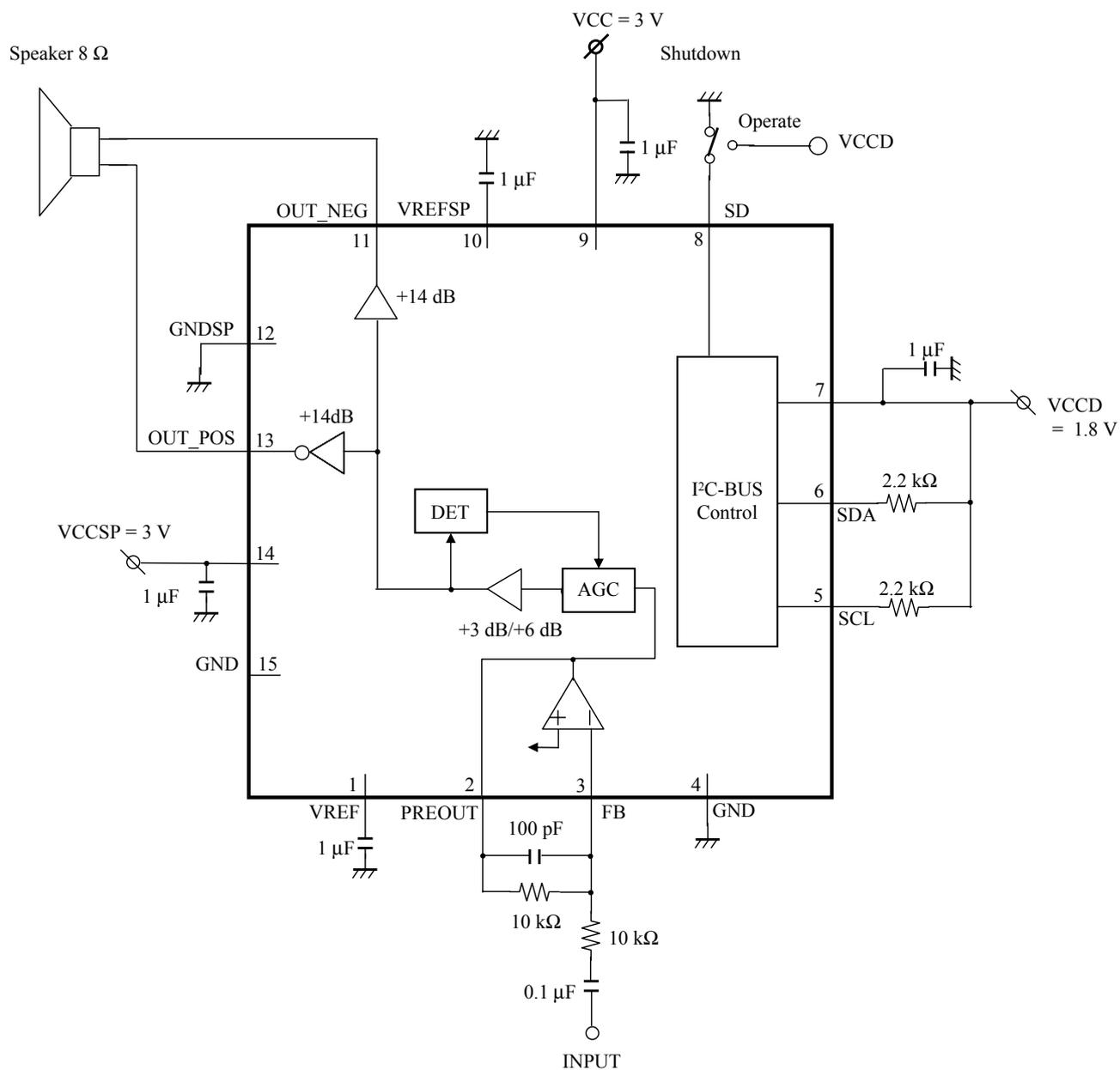
■ Package

- 15 pin Wafer level chip size package (WLCSP)
Size: 2.0 mm × 2.0 mm (0.5 mm pitch)

■ Type

- Bi-CMOS IC

■ Application Circuit Example (Block Diagram)



- Note) 1. This circuit and these circuit constants show an example and do not guarantee the design as a mass-production set.
 2. The threshold voltage at 8pin has the VCCD dependency.

■ Pin Descriptions

| Pin No. | Pin name | Type | Description |
|---------|----------|----------------|--|
| 1 | VREF | Output | Reference Voltage Output |
| 2 | PREOUT | Output | Pre-amplifier Output |
| 3 | FB | Input | Pre-amplifier Negative Feedback Input |
| 4 | GND | Ground | Ground |
| 5 | SCL | Input | SCL Input on I ² C-bus Control |
| 6 | SDA | Input / Output | SDA Input on I ² C-bus Control |
| 7 | VCCD | Power Supply | Power supply for logic circuit |
| 8 | SD | Input | Shutdown Control |
| 9 | VCC | Power Supply | Power supply |
| 10 | VREFSP | Output | Reference Voltage Output for Speaker Amplifier |
| 11 | OUT_NEG | Output | Speaker Output (Negative Phase) |
| 12 | GNDSP | Ground | Ground for Speaker Amplifier |
| 13 | OUT_POS | Output | Speaker Output (Positive Phase) |
| 14 | VCCSP | Power Supply | Power supply for Speaker Amplifier |
| 15 | GND | Ground | Ground |

■ Absolute Maximum Ratings

| A No. | Parameter | Symbol | Rating | Unit | Note |
|-------|-------------------------------|------------------|-------------|------|------|
| 1 | Supply voltage | VCC | 5.5 | V | *1 |
| | | VCCD | 3.6 | | |
| | | VCCSP | 5.5 | | |
| 2 | Supply current | I _{CC} | — | A | |
| 3 | Power dissipation | P _D | 120 | mW | *2 |
| 4 | Operating ambient temperature | T _{opr} | −20 to +70 | °C | *3 |
| 5 | Storage temperature | T _{stg} | −55 to +150 | °C | *3 |

Note) *1: The values under the condition not exceeding the above absolute maximum ratings and the power dissipation.

*2: The power dissipation shown is the value at T_a = 70°C for the independent (unmounted) IC package without a heat sink.

When using this IC, refer to the • P_D – T_a diagram in the ■ Technical Data and use under the condition not exceeding the allowable value.

*3: Except for the power dissipation, operating ambient temperature, and storage temperature, all ratings are for T_a = 25°C.

■ Operating Supply Voltage Range

| Parameter | Symbol | Range | Unit | Note |
|----------------------|--------|------------|------|------|
| Supply voltage range | VCC | 2.7 to 4.5 | V | |
| | VCCD | 1.7 to 2.6 | | *1 |
| | | 1.7 to 3.3 | | *2 |
| | VCCSP | 2.7 to 4.5 | | |

Note) 1. The values under the condition not exceeding the above absolute maximum ratings and the power dissipation.

2. *1: The values under Fast mode.

*2: The values under Standard mode.

■ Electrical Characteristics at VCC = 3.0 V , VCCD = 1.8 V , VCCSP = 3.0 V

Note) T_a = 25°C±2°C unless otherwise specified.

| B No. | Parameter | Symbol | Conditions | Limits | | | Unit | Note |
|------------------------------|--|--------|---|--------|------|------|------|------|
| | | | | Min | Typ | Max | | |
| Circuit Current | | | | | | | | |
| 1 | Circuit current at non-signal 1 (VCC) | IVCC1A | VCC = 3.0V, Non-signal STB = OFF, SP = ON, AGC = ON | 0.5 | 2.4 | 4.5 | mA | |
| 2 | Circuit current at non-signal 2 (VCCSP) | IVCC2A | VCCSP = 3.0V, Non-signal STB = OFF, SP = ON, AGC = ON | 1.0 | 6.5 | 15.5 | mA | |
| 3 | Circuit current at non-signal 3 (VCCD) | IVCC3A | VCCD = 1.8V, Non-signal STB = OFF, SP = ON, AGC = ON | — | 0.1 | 10 | μA | |
| 4 | Circuit current at standby mode 1 (VCC) | IVCC1B | VCC = 3.0V, Non-signal STB = ON, SP = OFF, AGC = ON | — | 0.1 | 1.0 | μA | |
| 5 | Circuit current at standby mode 2 (VCCSP) | IVCC2B | VCCSP = 3.0V, Non-signal STB = ON, SP = OFF, AGC = ON | — | 0.1 | 1.0 | μA | |
| 6 | Circuit current at standby mode 3 (VCCD) | IVCC3B | VCCD = 1.8V, Non-signal STB = ON, SP = OFF, AGC = ON | — | 0.1 | 1.0 | μA | |
| 7 | Circuit current at speaker save mode 1 (VCC) | IVCC1C | VCC = 3.0 V, Non-signal STB = OFF, SP = OFF, AGC = ON | 0.5 | 2.4 | 4.5 | mA | |
| 8 | Circuit current at speaker save mode 2 (VCCSP) | IVCC2C | VCCSP = 3.0 V, Non-signal STB = OFF, SP = OFF, AGC = ON | — | 0.3 | 1.0 | mA | |
| 9 | Circuit current at speaker save mode 3 (VCCD) | IVCC3C | VCCD = 1.8 V, Non-signal STB = OFF, SP = OFF, AGC = ON | — | 0.1 | 10 | μA | |
| Input/output characteristics | | | | | | | | |
| 11 | SP reference output level | VSPO | V _{in} = -31.0 dBV, f = 1 kHz RL = 8 Ω, GAIN = +23 dB | -9.5 | -8.0 | -6.5 | dBV | |
| 12 | SP reference output distortion | THSPO | V _{in} = -31.0 dBV, f = 1 kHz RL = 8 Ω, GAIN = +23dB to THD5th | — | 0.07 | 0.5 | % | |
| 13 | SP output noise voltage | VNSPO | Non-Signal using A curve filter GAIN = +23 Db | — | -78 | -71 | dBV | |
| 14 | SP maximum rating output | VMSP0 | THD = 10%, f = 1 kHz RL = 8Ω, AGC = OFF | 300 | 500 | — | mW | |
| 15 | SP output level at power save | VSSPO | V _{in} = -31.0 dBV, f = 1 kHz RL = 8 Ω, GAIN = +23 dB using A curve filter | — | -114 | -90 | dBV | |
| 16 | SP AGC output level 1 | VSPOA1 | V _{in} = -17.0 dBV, f = 1 kHz RL = 8 Ω, GAIN = +23 dB AGC-Level = 4 dBV | 3.0 | 4.0 | 5.0 | dBV | |
| 17 | SP AGC output level 2 | VSPOA2 | V _{in} = -12.0 dBV, f = 1 kHz RL = 8 Ω, GAIN = +23 dB AGC-Level = 4 dBV | 3.0 | 4.0 | 5.0 | dBV | |

■ Electrical Characteristics at VCC = 3.0 V , VCCD = 1.8 V , VCCSP = 3.0 V (continued)

Note) T_a = 25°C±2°C unless otherwise specified.

| B No. | Parameter | Symbol | Conditions | Limits | | | Unit | Note |
|--------------------------------|---------------------------------------|------------------|--------------------------------------|------------|-----|------------|------|------|
| | | | | Min | Typ | Max | | |
| I ² C interface | | | | | | | | |
| 43 | SCL, SDA signal input Low Level | V _{IL} | — | -0.5 | — | 0.3 × VCCD | V | |
| 44 | SCL, SDA signal input Low Level | V _{IH} | — | 0.7 × VCCD | — | VCCD + 0.5 | V | |
| 45 | SDA output signal Low Level | V _{OL} | Open corrector Sync current: 3 mA | 0 | — | 0.2 × VCCD | V | |
| 46 | SCL,SDA Signal Input Current | I _i | Input voltage: 0.1 V to 1.7 V | -10 | — | 10 | μA | |
| 47 | SCL maximum frequency of signal input | f _{SCL} | — | 0 | — | 400 | kHz | |
| The threshold voltage at 8-pin | | | | | | | | |
| 48 | SD input Low Level | Vresetlth | — | — | — | 0.1 × VCCD | V | |
| 49 | SD input High Level | Vresetsth | — | 0.9 × VCCD | — | — | V | |

■ Electrical Characteristics (Reference values for design) at VCC = 3.0 V , VCCD = 1.8 V , VCCSP = 3.0 V

Note) $T_a = 25^{\circ}\text{C} \pm 2^{\circ}\text{C}$ unless otherwise specified.

The characteristics listed below are reference values derived from the design of the IC and are not guaranteed by inspection.

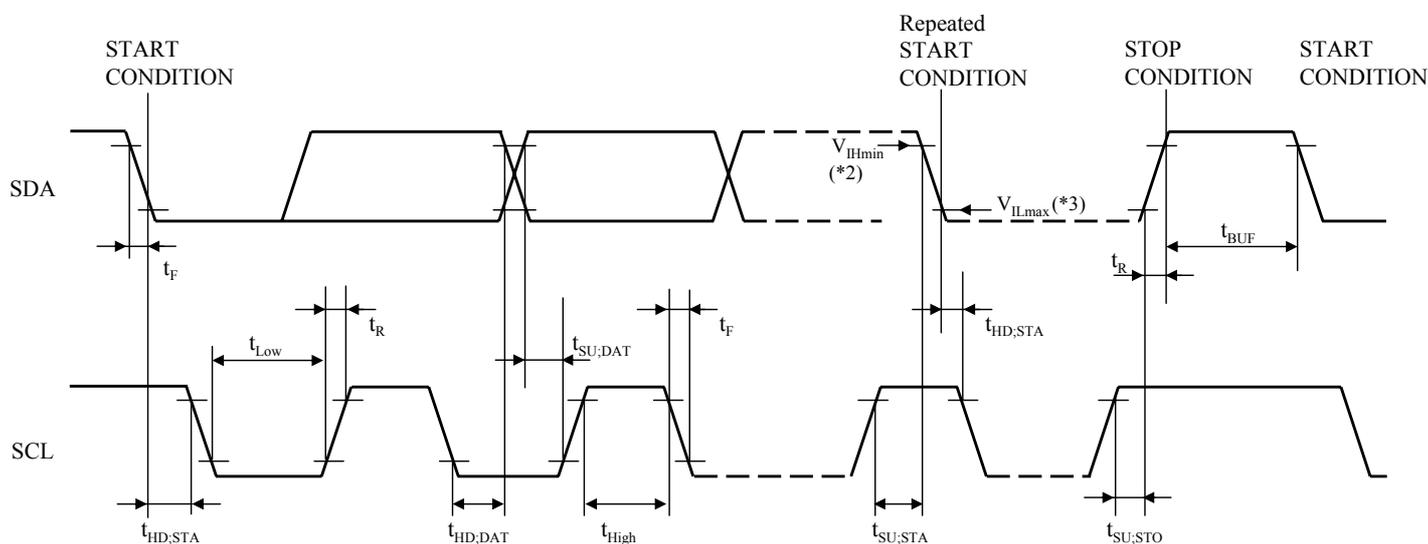
If a problem does occur related to these characteristics, we will respond in good faith to user concerns.

| B No. | Parameter | Symbol | Conditions | Limits | | | Unit | Note |
|----------------------------|--|---------------------|------------|--------|-----|-----|---------------|------|
| | | | | Min | Typ | Max | | |
| I ² C interface | | | | | | | | |
| 66 | Bus free time between a condition of stop and a condition of start | t_{BUF} | — | 1.3 | — | — | μs | *1 |
| 67 | Setup time of a condition of start | $t_{\text{SU,STA}}$ | — | 0.6 | — | — | μs | *1 |
| 68 | Hold time of a condition for start | $t_{\text{HD,STA}}$ | — | 0.6 | — | — | μs | *1 |
| 69 | "L" time of SCL clock | t_{Low} | — | 1.3 | — | — | μs | *1 |
| 70 | "H" time of SCL clock | t_{High} | — | 0.6 | — | — | μs | *1 |
| 71 | Rising time of SDA, SCL signal | t_{R} | — | — | — | 0.3 | μs | *1 |
| 72 | Fall time of SDA, SCL signal | t_{F} | — | — | — | 0.3 | μs | *1 |
| 73 | Data setup time | $t_{\text{SU,DAT}}$ | — | 0.1 | — | — | μs | *1 |
| 74 | Data hold time | $t_{\text{HD,DAT}}$ | — | 0 | — | 0.9 | μs | *1 |
| 75 | Rising up time of a condition of stop | $t_{\text{SU,STO}}$ | — | 0.6 | — | — | μs | *1 |

Note) *1: All values are V_{IHmin} (*2) and V_{ILmax} (*3) level standard.

*2: V_{IHmin} is the minimum limit of the signal input high level.

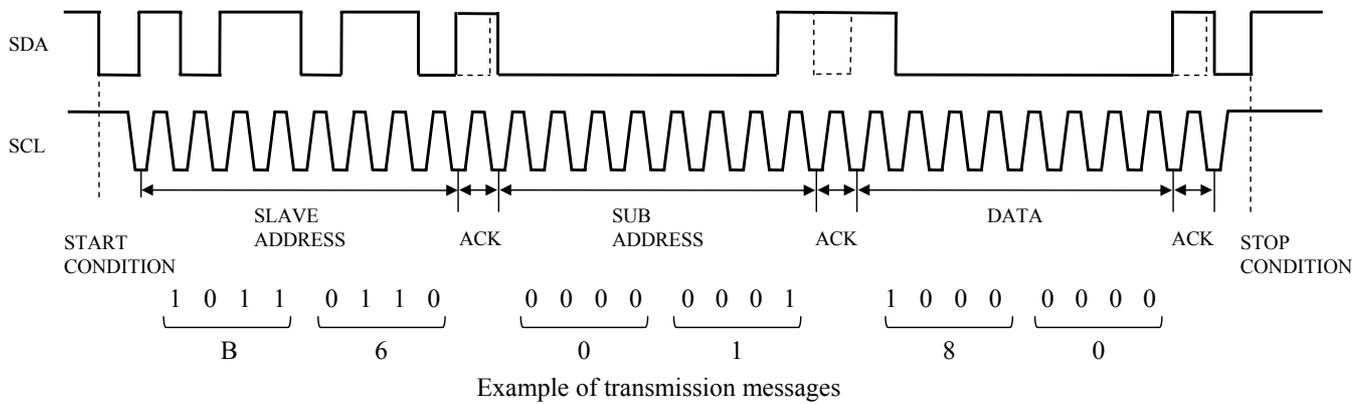
*3: V_{ILmax} is the maximum limit of the signal input low level.



■ Technical Data

• I²C-bus Mode

1. Write Mode



Two transmission messages (i.e., the SCL and SDA) are sent in synchronous serial transmission. The SCL is a clock with fixed frequency. The SDA indicates address data for the control of the reception side, and is sent in parallel in synchronization with the SCL. The data is transmitted in 8-bit, 3 octets (bytes) in principle, where every octet has an acknowledge bit. The following description provides information on the structure of the frame.

<Start Conditions>

When the level of the SDA changes to low from high while the level of the SCL is high, the data reception of the receiver will be enabled.

<Stop Conditions>

When the level of the SDA changes to high from low while the level of the SCL is high, the data reception of the receiver will be aborted.

<Slave Address>

The slave address is a specified one unique to each device. When the address of another device is sent, the reception will be aborted.

<Sub Address>

The sub address is a specified one unique to each function.

<Data>

Data is information under control.

<Acknowledge Bit>

The acknowledge bit is used to enable the master to acknowledge the reception of data for each octet. The master acknowledges the data reception of the receiver by transmitting a high-level signal to the receiver and receiving a low-level signal returned from the receiver as shown by the dotted lines in Fig.

The communication will be aborted if the low signal is not returned.

The SDA will not change when the level of the SCL is high except start or stop conditions are enabled.

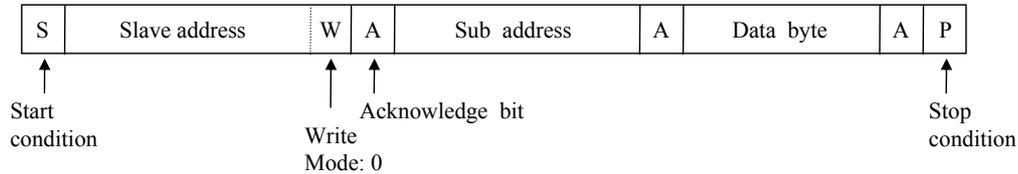
■ Technical Data (continued)

• I²C-bus Mode (continued)

1. Write Mode (continued)

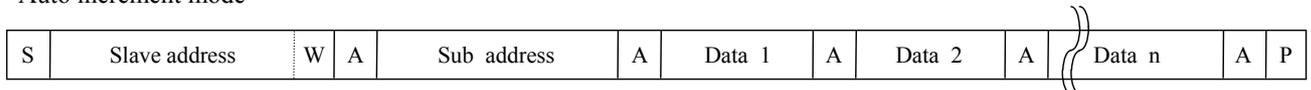
(a) I²C-bus PROTOCOL

- Slave address: 10110110 (B6Hex)
- Format (normal)



(b) Auto increment

- Sub-address 0*Hex: Auto increment mode
(When the data is sent in sequence, the sub address will change one by one and the data will be input.)
- Auto increment mode



(c) Initial condition

The initial state of the device is not guaranteed. Therefore, the input of 00Hex register-D0 (Note.1) will be absolutely 0, when the power is turned ON.

(d) Sub-address Byte and Data Byte Format

| Sub-address | Data byte | | | | | | | |
|-------------|--------------------------------|--|---------------------|----------------------|--------------------------|------------------------------|------------------------------|----------------------|
| | MSB | | | | | | | LSB |
| | D7 | D6 | D5 | D4 | D3 | D2 | D1 | D0 |
| *0Hex | GAIN 0 → +23dB 1 → +26dB | AGC-ON VCCSP dependence 0 → OFF 1 → ON | 0 (Note.2) | 0 (Note.2) | AGC 0 → OFF 1 → ON | SP Save 0 → ON 1 → OFF | Standby 0 → ON 1 → OFF | 0 (Note.1) |
| *1Hex | AGC-ON data bit3 | AGC-ON data bit2 | AGC-ON data bit1 | AGC-REC data bit3 | AGC-REC data bit2 | AGC-REC data bit1 | AGC-ATT data bit2 | AGC-ATT data bit1 |
| *2Hex | 0 (Note.2) | 0 (Note.2) | 0 (Note.2) | * | * | 0 (Note.2) | 0 (Note.2) | 0 (Note.2) |

<00Hex Register>

- D0, D4, D5: Always set to 0
- D1: Standby ON/OFF switch
- D2: SP Save ON/OFF switch
- D3: AGC ON/OFF switch
- D6: AGC-ON VCCSP dependence ON/OFF selection
- D7: GAIN +17 dB/+20 dB selection

<01Hex Register>

- D0, D1 : AGC-attack-time selection
- D2, D3,D4: AGC-recovery-time selection
- D5,D6,D7: AGC-on-level selection

<02Hex Register>

- D0 to D7: Always set to 0 (test & adjust mode)

0
(Note.2)



Please use these bit only Data = "0", because they are used by our company's final test and fine-tuning AGC-on level.

■ Technical Data (continued)

• I²C-bus Mode (continued)

1. Write Mode (continued)

(e) AGC-attack-time selection

| Write 01Hex Register | | Attack time |
|----------------------|----|-------------|
| D1 | D0 | |
| 0 | 0 | 0.5 ms |
| 0 | 1 | 1 ms |
| 1 | 0 | 2 ms |
| 1 | 1 | 4 ms |

(f) AGC-recovery-time selection

| Write 01Hex Register | | | Recovery time |
|----------------------|----|----|---------------|
| D4 | D3 | D2 | |
| 0 | 0 | 0 | 1.0 s |
| 0 | 0 | 1 | 1.5 s |
| 0 | 1 | 0 | 2.0 s |
| 0 | 1 | 1 | 3.0 s |
| 1 | 0 | 0 | 4.0 s |
| 1 | 0 | 1 | 6.0 s |
| 1 | 1 | 0 | 8.0 s |
| 1 | 1 | 1 | 12.0 s |

(g) AGC-on-level selection (at VCC = 3.0 V, VCCSP = 3.0 V)

| Write 01Hex Register | | | AGC On Level | Output Po (RL = 8W) | VCCSP (推奨値) |
|----------------------|----|----|--------------|-----------------------|-------------|
| D7 | D6 | D5 | | | |
| 0 | 0 | 0 | 1 dBV | 157 mW | — |
| 0 | 0 | 1 | 2 dBV | 198 mW | — |
| 0 | 1 | 0 | 3 dBV | 249 mW | — |
| 0 | 1 | 1 | 4 dBV | 314 mW | 3.0 V ≤ |
| 1 | 0 | 0 | 5 dBV | 395 mW | 3.3 V ≤ |
| 1 | 0 | 1 | 6 dBV | 498 mW | 3.7 V ≤ |
| 1 | 1 | 0 | 7 dBV | 626 mW | 4.1 V ≤ |
| 1 | 1 | 1 | 8 dBV | 789 mW | 4.5 V |

(h) AGC-on-level VCCSP dependence mode (at AGC On Level = 4 dBV)

AGC ON level increases by 0.75 dBV with each 0.3 V increase of VCCSP, and baseline of VCCSP is 3.0 V at AGC-on-level VCCSP dependence mode. When VCCSP is 3.0 V, AGC ON level is set according to table (g).

| VCCSP | AGC On Level | Output Po (RL = 8 Ω) | VCCSP | AGC On Level | Output Po (RL = 8 Ω) |
|-------|--------------|------------------------|-------|--------------|------------------------|
| 2.7 V | 3.25 dBV | 264 mW | 3.9 V | 6.25 dBV | 527 mW |
| 3.0 V | 4 dBV | 314 mW | 4.2 V | 7 dBV | 626 mW |
| 3.3 V | 4.75 dBV | 373 mW | 4.5 V | 7.75 dBV | 745 mW |
| 3.6 V | 5.5 dBV | 444 mW | | | |

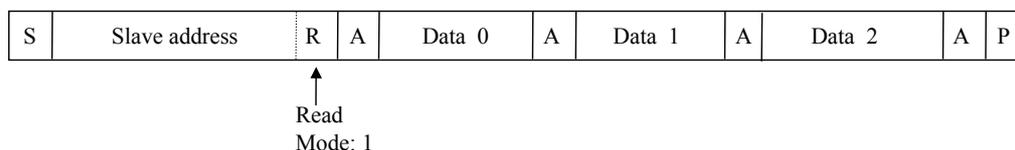
■ Technical Data (continued)

• I²C-bus Mode (continued)

2. Read Mode

(a) I²C-bus PROTOCOL

- Slave address 10110111(B7Hex)
- Format



Note) At the slave address input, it is sequentially output from data 0.
There is no necessity for inputting the sub-address.

(b) Sub-address Byte and Data Byte Format

| | Data byte | | | | | | | |
|--------|--|--|--|--|--|--|--|--|
| | MSB | | | | | | | LSB |
| | D7 | D6 | D5 | D4 | D3 | D2 | D1 | D0 |
| Data 0 | Sub address *0Hex Latch data [D7] | Sub address *0Hex Latch data [D6] | Sub address *0Hex Latch data [D5] | Sub address *0Hex Latch data [D4] | Sub address *0Hex Latch data [D3] | Sub address *0Hex Latch data [D2] | Sub address *0Hex Latch data [D1] | Sub address *0Hex Latch data [D0] |
| Data 1 | Sub address *1Hex Latch data [D7] | Sub address *1Hex Latch data [D6] | Sub address *1Hex Latch data [D5] | Sub address *1Hex Latch data [D4] | Sub address *1Hex Latch data [D3] | Sub address *1Hex Latch data [D2] | Sub address *1Hex Latch data [D1] | Sub address *1Hex Latch data [D0] |
| Data 2 | Sub address *2Hex Latch data [D7] | Sub address *2Hex Latch data [D6] | Sub address *2Hex Latch data [D5] | Sub address *2Hex Latch data [D4] | Sub address *2Hex Latch data [D3] | Sub address *2Hex Latch data [D2] | Sub address *2Hex Latch data [D1] | Sub address *2Hex Latch data [D0] |

• Operating temperature guarantee of I²C-bus Control

The performance in the ambient temperature of operation is guaranteed theoretically in the design at normal temperature (25°C) by inspecting it at a speed of the clock that is about 50% earlier regarding the operating temperature guarantee of I²C-bus Control.

But the following characteristics are logical values derived from the design of the IC and are not guaranteed by inspection.
If a problem does occur related to these characteristics, Panasonic will respond in good faith to customer concerns.

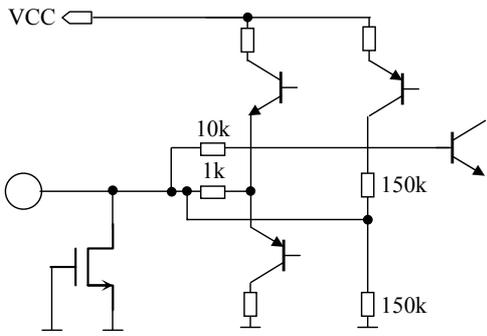
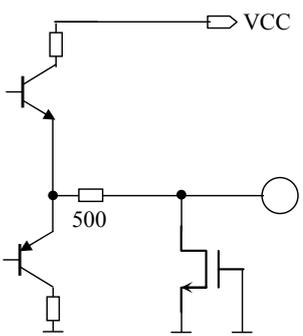
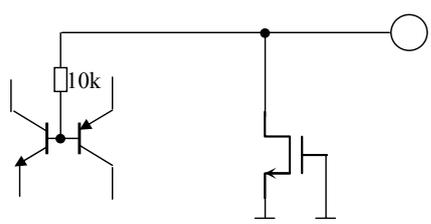
• Usage note of I²C bus

- The I²C bus of this product is designed to correspond to Standard mode (100 Kbps) and Fast mode (400 Kbps) in Philips Corporation I²C specification version 2.1. However, not correspond to High Speed mode (to 3.4 Mbps).
- This product operate as a slave device in I²C bus system.
- This product is not confirm to operate in multi-master bus system and mixing -speed bus system. And this product is not confirm connectivity to CBUS receiver. If using this product in these mode, please confirm availability to our company.
- Purchase of Panasonic I²C components conveys a license to use these components in an I²C systems under the Philips I²C patent right on condition that using condition conform to I²C standard specification approved by Philips Corporation.

■ Technical Data (continued)

- I/O block circuit diagrams and pin function descriptions

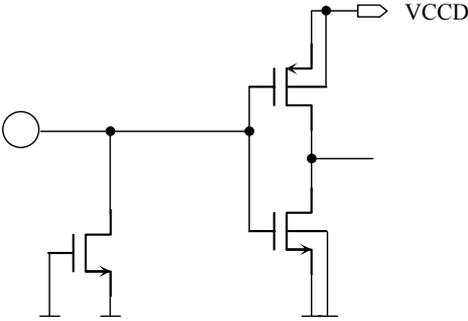
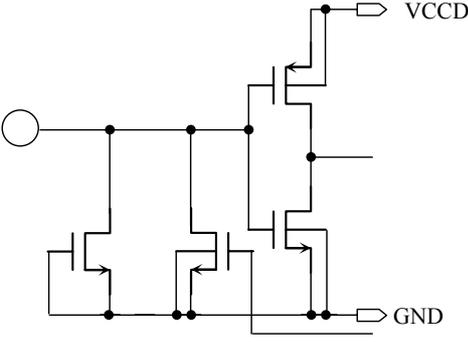
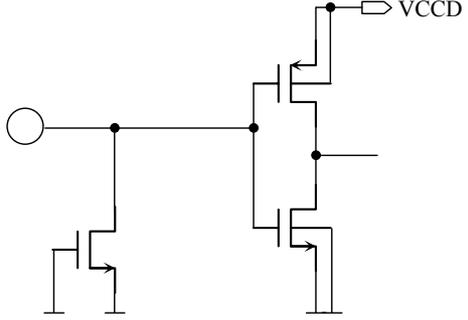
Note) The characteristics listed below are reference values based on the IC design and are not guaranteed.

| Pin No. | Waveform and voltage | Internal circuit | Description |
|---------|----------------------|---|---------------------------------------|
| 1 | VREF DC 1.45 V |  | Reference Voltage Output |
| 2 | PREOUT DC 1.45 V |  | Pre-amplifier Output |
| 3 | FB DC 1.45 V |  | Pre-amplifier Negative Feedback Input |
| 4 | GND | — | Ground |

■ Technical Data (continued)

• I/O block circuit diagrams and pin function descriptions (continued)

Note) The characteristics listed below are reference values based on the IC design and are not guaranteed.

| Pin No. | Waveform and voltage | Internal circuit | Description |
|---------|---|--|---|
| 5 | SCL Hi-Z |  | SCL Input on I ² C-Bus Control |
| 6 | SDA Hi-Z |  | SDA Input on I ² C-Bus Control |
| 7 | VCCD 1.8 V(typ.) | — | Power Supply for Logic Circuit |
| 8 | SD Connect VCCD to VCC 1.8 V to 3.0 V |  | Shutdown Control Shutdown mode is shorted to GND. (All data becomes 0.) |

■ Technical Data (continued)

• I/O block circuit diagrams and pin function descriptions (continued)

Note) The characteristics listed below are reference values based on the IC design and are not guaranteed.

| Pin No. | Waveform and voltage | Internal circuit | Description |
|---------|-----------------------|------------------|--|
| 9 | VCC 3.0 V(typ.) | — | Power Supply |
| 10 | VREFSP 3.0 V(typ.) | | Reference Voltage Output for Speaker Amplifier |
| 11 | OUT_NEG DC 1.45 V | | Speaker Output (Negative Phase) |
| 12 | GNDSP | — | Ground for Speaker Amplifier |

■ Technical Data (continued)

- I/O block circuit diagrams and pin function descriptions (continued)

Note) The characteristics listed below are reference values based on the IC design and are not guaranteed.

| Pin No. | Waveform and voltage | Internal circuit | Description |
|---------|----------------------|------------------|---------------------------------------|
| 13 | OUT_POS DC 1.45 V | | Speaker Output (Positive Phase) |
| 14 | VCCSP 3.0 V(typ.) | — | Power Supply for Speaker Amplifier |
| 15 | GND | — | Ground |

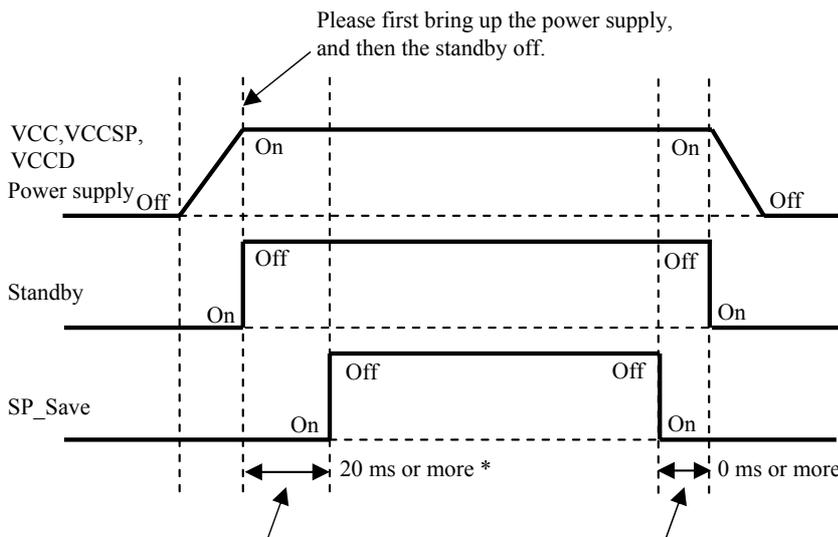
■ Technical Data (continued)

• Power supply and logic sequence

Note) The characteristics listed below are reference values based on the IC design and are not guaranteed.

The timing control of power-ON/OFF and each logic according to the procedure below should be recommended for the best pop performance caused in switching.

1. The sequence of the power supply and each logic



The basic procedure at the power-on

1. The power OFF condition
Both the standby and the SP_Save are in the ON condition.
2. Power ON
3. Standby Off
4. SP_Save Off

The basic procedure at the power-off

1. The power ON condition
Both the standby and the SP_Save are in the OFF condition.
2. SP_Save On (= Standby On)
3. Standby On
4. Power Off

After at least 20 ms has passed after the standby off, please off SP_Save.

Please control Standby On to simultaneous with SP_Save On, or the back.

Note) *: This IC contains the pre-charge circuit. It is time until each bias is stabilized from Standby Off.

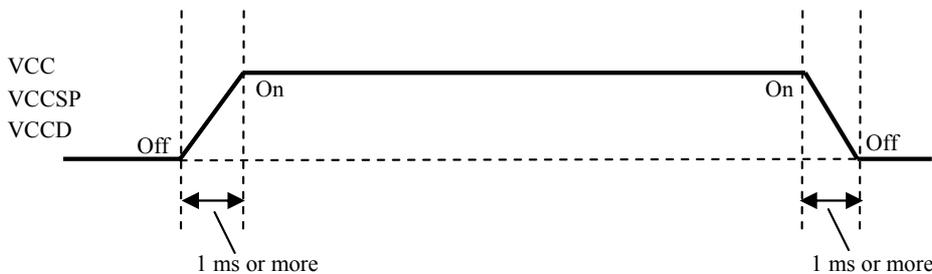
It depends for this time on the capacity value linked to a reference voltage terminal (VREF and VREFSP), and the capacity value and resistance linked to an input terminal (IN).

It is a recommendation value in a constant given in the example of ■ Application Circuit Example (Block Diagram).

2. The sequence of VCC and VCCSP and VCCD

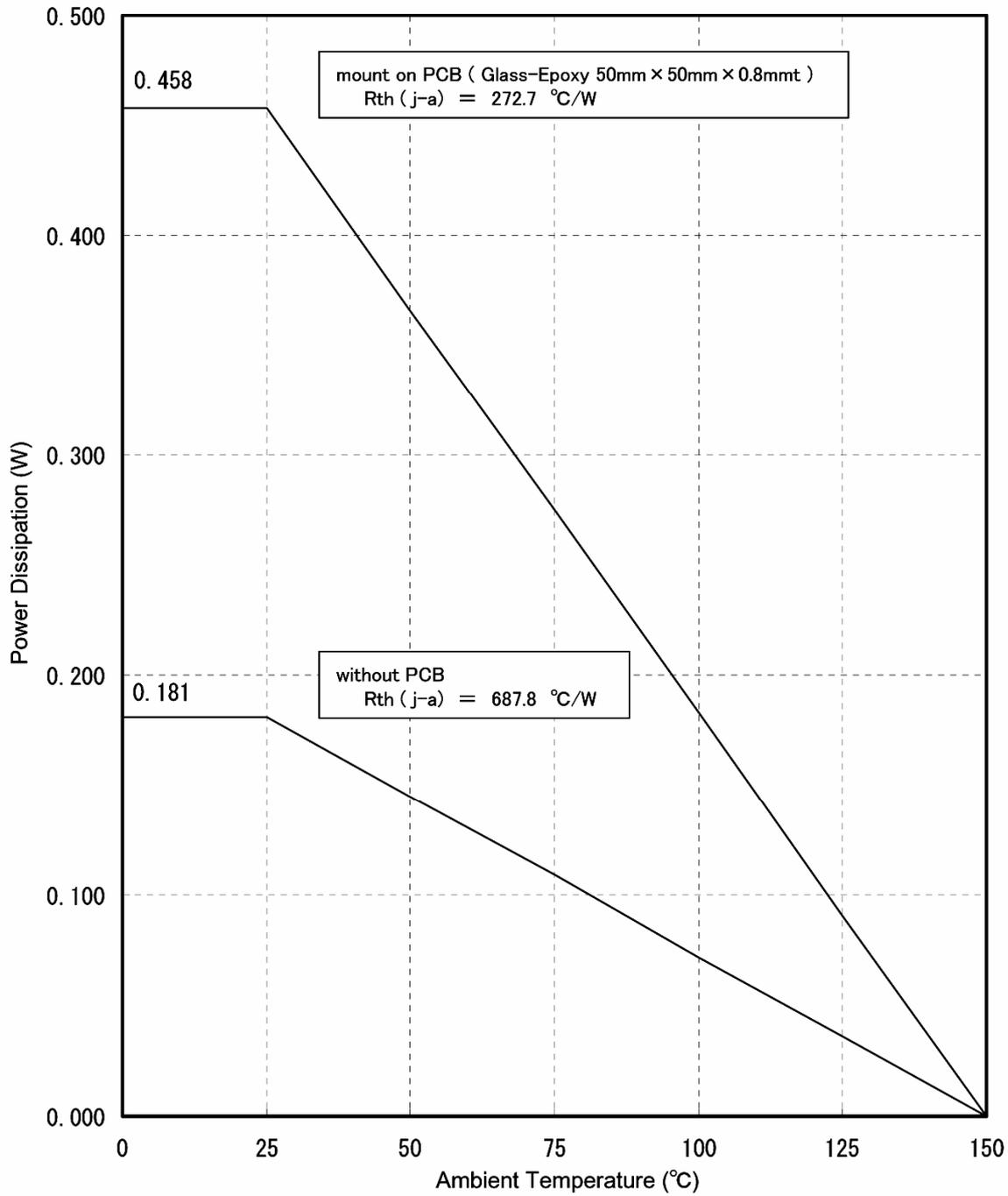
This IC have not a standup and falling order in VCC and VCCSP.

A standup and falling time of VCC and VCCSP recommend 1 or more ms.



■ Technical Data (continued)

- P_D — T_a diagram



■ Usage Notes

1. Please take notice in the use of this product that it might break or occasionally smoke when an abnormal state occurs such as SP output pin (Pin11, Pin13) – power supply pin short, SP output pin (Pin11, Pin13) – GND short, or SP output (Pin11, Pin13) -to-SP output-pin short (load short).
2. Please absolutely do not mount the IC in the reverse direction on to the printed-circuit-board.
It damaged when the electricity is turned on.
3. Please do not make it open, because the open SD-pin (Pin8) is not fixed.

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